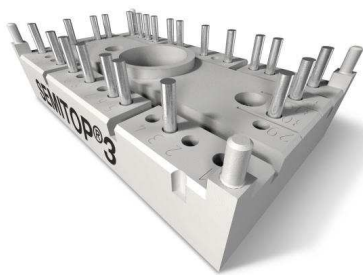


SK 70 DT



SEMITOP® 3

Controlled Bridge Rectifier

SK 70 DT

Preliminary Data

Features

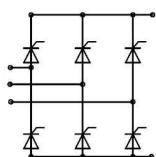
- Compact design
- One screw mounting
- Heat transfer and insulation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications*

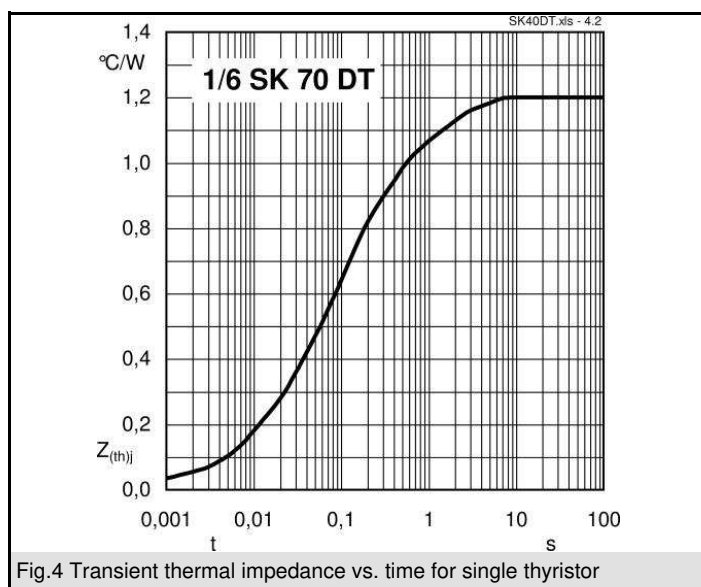
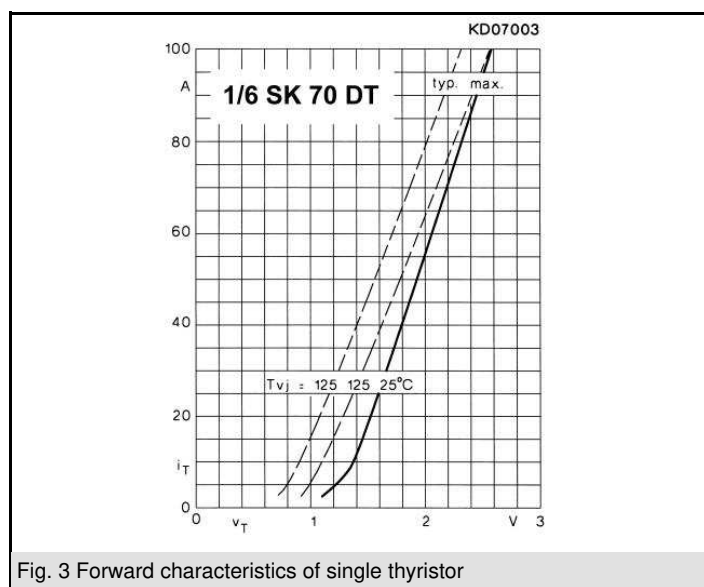
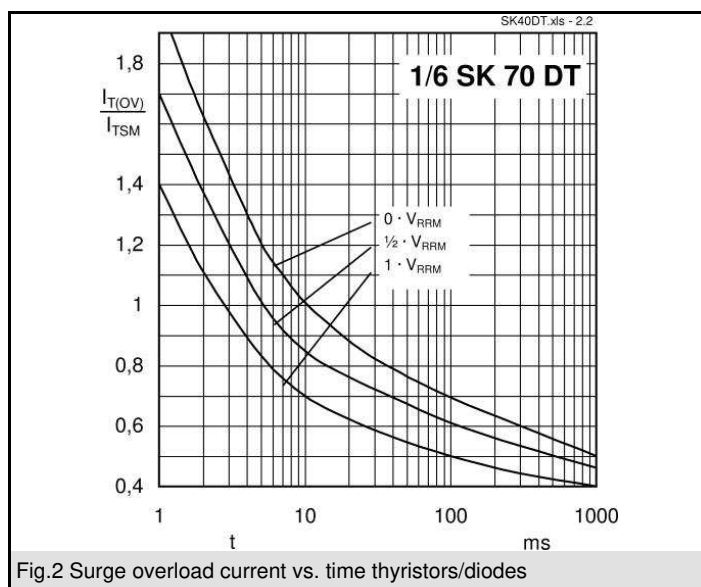
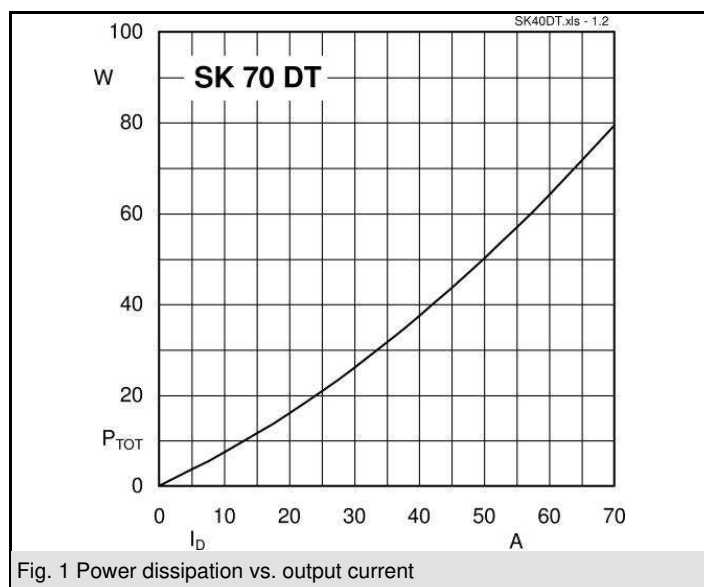
- Soft starters
- Light control
- Temperature control
- Motor control

V_{RSM} V	V_{RRM}, V_{DRM} V	$I_D = 68 \text{ A}$ (full conduction) ($T_s = 80^\circ \text{C}$)
900	800	SK 70 DT 08
1300	1200	SK 70 DT 12
1700	1600	SK 70 DT 16

Symbol	Conditions	Values	Units
I_D	$T_s = 80^\circ \text{C}$	68	A
I_{TSM}	$T_{vj} = 25^\circ \text{C}; 10 \text{ ms}$ $T_{vj} = 125^\circ \text{C}; 10 \text{ ms}$	450 380	A A
i^2t	$T_{vj} = 25^\circ \text{C}; 8,3 \dots 10 \text{ ms}$ $T_{vj} = 125^\circ \text{C}; 8,3 \dots 10 \text{ ms}$	1000 720	A^2s A^2s
V_T	$T_{vj} = 25^\circ \text{C}; 75\text{A}$	max. 1,9	V
$V_{T(TO)}$	$T_{vj} = 125^\circ \text{C};$	max. 1	V
r_T	$T_{vj} = 125^\circ \text{C}$	max. 10	$\text{m}\Omega$
I_{DD}, I_{RD}	$T_{vj} = 125^\circ \text{C}; V_{DD} = V_{DRM}; V_{RD} = V_{RRM}$	max. 10	mA
t_{gd}	$T_{vj} = 25^\circ \text{C}; I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu\text{s}$	1	μs
t_{gr}	$V_D = 0,67 \cdot V_{DRM}$	2	μs
$(dv/dt)_{cr}$	$T_{vj} = 125^\circ \text{C}$	max. 1000	$\text{V}/\mu\text{s}$
$(di/dt)_{cr}$	$T_{vj} = 125^\circ \text{C}; f = 50 \dots 60 \text{ Hz}$	max. 50	$\text{A}/\mu\text{s}$
t_q	$T_{vj} = 125^\circ \text{C}; \text{typ.}$	80	μs
I_H	$T_{vj} = 25^\circ \text{C}; \text{typ.} / \text{max.}$	80 / 150	mA
I_L	$T_{vj} = 25^\circ \text{C}; R_G = 33 \Omega$	150 / 300	mA
V_{GT}	$T_{vj} = 25^\circ \text{C}; \text{d.c.}$	min. 2	V
I_{GT}	$T_{vj} = 25^\circ \text{C}; \text{d.c.}$	min. 100	mA
V_{GD}	$T_{vj} = 125^\circ \text{C}; \text{d.c.}$	max. 0,25	V
I_{GD}	$T_{vj} = 125^\circ \text{C}; \text{d.c.}$	max. 3	mA
$R_{th(j-s)}$	Per thyristor	1,2	K/W
T_{solder}	Terminals, 10s	260	K/W $^\circ \text{C}$
T_{vj}		-40...+125	$^\circ \text{C}$
T_{stg}		-40...+125	$^\circ \text{C}$
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 (2500)	V
M_s	Mounting torque to heatsink	2,5	Nm
m	weight	30	g
Case	SEMITOP® 3	T 15	



DT



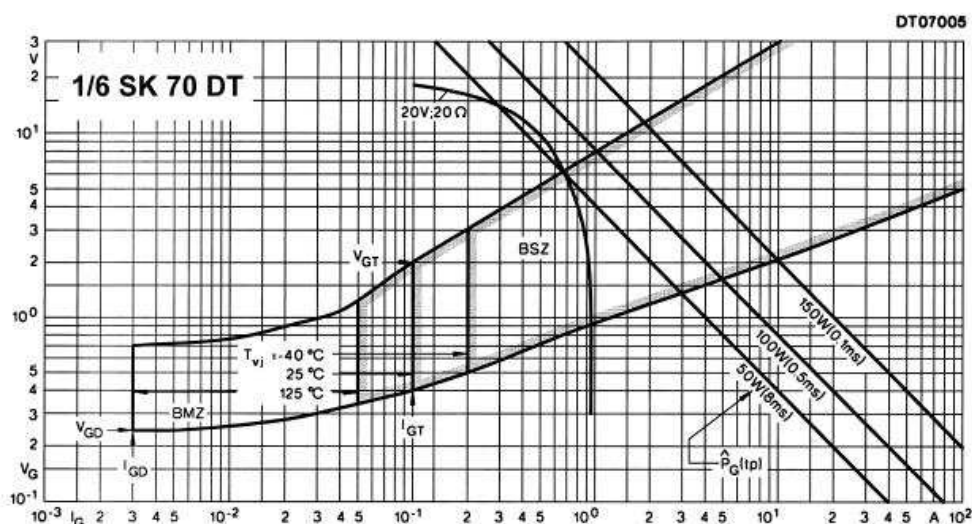
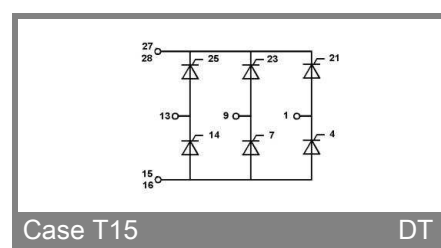
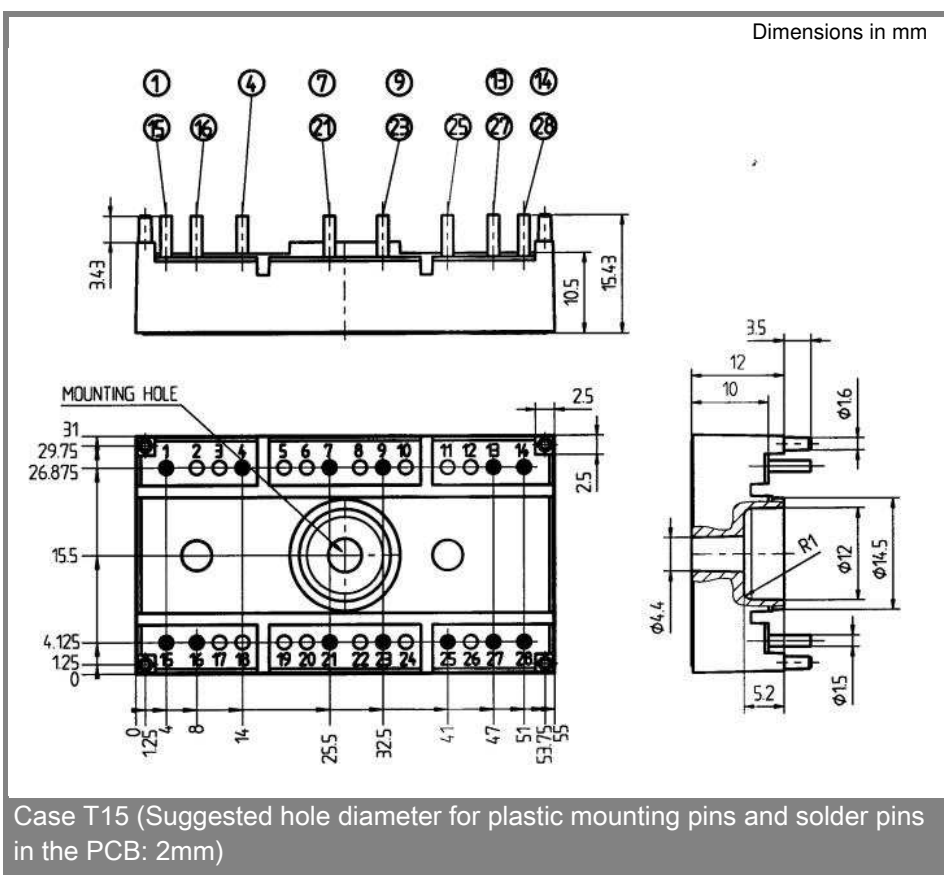


Fig. 5 Gate trigger characteristics



* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.